

Quarterly Reliability Monitoring Results

Quarters: Q1/2022 to Q4/2023

Based on structural similarity

	User Part Number					
	PNU65010EP-Q Part Description					
boratory						
	Nexperia DHAM	Rectifier				
iability labs	SMD package					
EC-Q101 Test	Test Conditions	Duration	# Lots	# Quantity	# Rejects	
TEST						
Pre- and Post-Stress						
Electrical Test	Tamb = 25 °C	N/A	see below	all parts	see below	
	JESD22-A113					
					_	
Preconditioning		3 cycles	1514	64430	0	
		1000 hours	40	1940	0	
Bid3	Teverse voltage	1000 110015	40	1040	U	
TC	JESD22-Δ104					
Temperature Cycling	-65 °C to Timax, not to exceed 150°C	1000 cycles	311	14080	0	
, , ,		1000 0,000	011	1.000		
UHAST	JESD22-A118					
Unbiased HAST	Tamb = 130 °C, RH = 85 %	96 hours	311	14080	0	
	JESD22-A102					
AC	Tamb = 121 °C, RH = 100 %					
Autoclave	Pressure = 205 kPa (29.7 psia)					
H3TRB	JESD22-A101					
Temperature Reverse Bias		1000 hours	311	14080	0	
					_	
Intermittent Operating Life	100 °C for 15000 cycles	1000 hours	312	14120	0	
DCH	JECD22 A111					
		10.6	260	9070	0	
	200 0 = 3 0	10.5	209	00/0	U	
Solderability	J-STD-002		222	6660	0	
	iability labs EC-Q101 Test TEST Pre- and Post-Stress Electrical Test PC Preconditioning HTRB High Temperature Reverse Bias TC Temperature Cycling UHAST Unbiased HAST AC Autoclave H3TRB High Humidity High Temperature Reverse Bias IOL Intermittent Operating Life RSH Resistance to Solder Heat SD	PNU65010EP-Q boratory Part Description Nexperia DHAM SMD package EC-Q101 Test Test Pre- and Post-Stress Electrical Test Tamb = 25 °C JESD22-A113 Bake Tamb = 125 °C PC Soak Tamb = 85 °C, RH = 85% Preconditioning MIL-STD-750-1 M1038 Method A High Temperature Reverse Bias TC Temperature Cycling TC Temperature Cycling JESD22-A104 -65 °C to Tjmax, not to exceed 150°C UHAST Unbiased HAST JESD22-A118 Tamb = 130 °C, RH = 85 % JESD22-A102 AC Autoclave H3TRB High Humidity High Temperature Reverse Bias JESD22-A101 Tamb = 85 °C, RH = 85 % JESD22-A102 Tamb = 121 °C, RH = 100 % Pressure = 205 kPa (29.7 psia) MIL-STD-750 Method 1037 ton = toff, devices powered to insure ΔTj = 100 °C for 15000 cycles RSH Resistance to Solder Heat JESD22-A111 Z60 °C ± 5 °C	PNU65010EP-Q Part Description Nexperia DHAM Rectifier	PNU65010EP-Q Part Description Nexperia DHAM SMD package	PNU65010EP-Q Part Description Nexperia DHAM SMD package SMD package SMD package SEC-Q101 Test Test Conditions Duration # Lots # Quantity TEST Pre- and Post-Stress Electrical Test Tamb = 25 °C N/A see below all parts Seb Periodition Soak Tamb = 85 °C, RH = 85% 168 hours 168	

^[1] The maximum applied voltage is limited by test chamber set up and does not exceed 115V.

Calculation of FIT and MTTF

Test considered for FIT calculation: High Temperature Reverse Bias (HTRB, Test #B1) Confidence level 60%, derated to 55 °C, activation energy 0.7 eV, test time 168 to 1000 hours

Wafer Fab	Technology	Quantity	Rejects	Failure Rate (FIT)	MTTF (hrs)
Nexperia					
DHAM	Rectifier	1840	0	2,31	4,33E+08

^{© 2024} Nexperia B.V.

All information hereunder is per Nexperia's best knowledge. This document does not provide for any representation or warranty express or implied by Nexperia. In case Nexperia has tested the product, this documentation reflects the outcome of the analysis of the actually tested parts only.

nexperia.com